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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/644,685	08/20/2003	Trung T. Doan	2269-3414.7US (97-1039.07	6457
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TRASK BRI	TT		NADAV, ORI	
P.O. BOX 255	50			
SALT LAKE CITY, UT 84110			ART UNIT	PAPER NUMBER
			2811	

DATE MAILED: 05/03/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
Office Assista Comments	10/644,685	DOAN ET AL.				
Office Action Summary	Examiner	Art Unit				
	Ori Nadav	2811				
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).						
Status						
1) Responsive to communication(s) filed on 14 Fe	bruary 2006.					
2a) ☐ This action is FINAL . 2b) ☑ This						
3) Since this application is in condition for allowant	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) Claim(s) is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.						
Priority under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary (Paper No(s)/Mail Da' 5) Notice of Informal Pa 6) Other:					
S. Patent and Trademark Office						

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-10, 12-18, 21-28, 30-37, 56-61 and 63-70, are rejected under 35 U.S.C. 103(a) as being unpatentable over McCollum (5,057,451) in view of Ovshinsky et al. (5,296,716).

MaCollum teaches in figure 1c and related text an integrated circuit device comprising:

a first conductive layer 12 including at least one protrusion;

an insulative layer 14 overlying the first conductive layer and exposing at least part of the at least one protrusion, and

a programmable resistive material 16 overlying at least part of the insulative layer and in direct contact with said at least one protrusion of said first conductive layer,

wherein the exposed part of the at least one protrusion comprises a smaller cross-sectional area than a remaining part of the at least one protrusion of said at least one conductive layer,

a second conductive layer 28 above the programmable resistive material,

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MaCollum does not teach a programmable resistive material comprises a chalcogenide material that is formulated to be reversibly cycled and thus capable of switching between at least two different resistive states.

Ovshinsky et al. teach in figure 1 and related text a programmable resistive material 36 comprises a chalcogenide material that is formulated to be reversibly cycled and thus capable of switching between at least two different resistive states. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use a programmable resistive material comprises a chalcogenide material that is formulated to be reversibly cycled and thus capable of switching between at least two different resistive states, in MaCollum's device in order to improve the characteristics and the operation of the device. The combination is motivated by the teachings of Ovshinsky et al. who point out the advantages of using a programmable resistive material comprises a chalcogenide material.

Regarding claims 2, 5, 9, 10, 12, 13, 14, 24, 27-28, 30-32, 58, 61, 63-65 and 70, the device of MaCollum and Ovshinsky et al. includes a programmable resistive material formulated to be reversibly cycled between at least two different resistive states,

wherein the chalcogenide material is selected from a group consisting of tellurium (Te), gennanium (Ge), antimony (Sb), and combinations thereof,

wherein the second conductive layer 38 comprises titanium nitride or carbon, a conductive barrier layer between said programmable resistive material and said second conductive layer.

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a second conductive layer above the programmable resistive material and an interlayer dielectric over the second conductive layer, the interlayer dielectric including an aperture that exposes at least a portion of an upper surface of said second conductive layer, and

conductive grid interconnect within said aperture, wherein said conductive grid interconnect is selected from the group consisting of titanium, titanium nitride and aluminum.

Regarding claims 6-7, 15-18, 25-26, 33-36, 59-60 and 66-69, MaCollum and Ovshinsky et al. do not teach the chalcogenide material includes tellurium (Te), gennanium (Ge), and antimony (Sb) in a ratio of TeaGebSb100-(a+b), where a, b, and 100-(a+b) are in atomic percentages which total 100% of the constituent elements and a <=70 and 15<=b,=50, wherein 40<=a<=60 and 17<=b<=44, and a portion of said at least one protrusion comprises a frustoconical tip having a frustum lateral dimension of at least 0.1 and 0.4 microns and a height of approximately 2000A.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to use a chalcogenide material includes tellurium (Te), gennanium (Ge), and antimony (Sb) in a ratio of TeaGebSb100-(a+b), where a, b, and 100-(a+b) are in atomic percentages which total 100% of the constituent elements and a <=70 and 15<=b,=50, wherein 40<=a<=60 and 17<=b<=44, and a portion of said at least one protrusion comprises a frustoconical tip having a frustum lateral dimension of at least 0.1 and 0.4 microns and a height of approximately 2000A in the device of MaCollum

and Ovshinsky et al., in order to optimize the characteristics of the device since it is within the skills of an artisan to improve the operation and characteristics of the device, subject to routine experimentation and optimization.

Regarding claim 21, MaCollum teaches in figure 1c and related text an integrated circuit device comprising:

a first electrode 12 having a first portion and a second portion, a width of the first electrode narrowing substantially and continuously in a direction extending from the second portion toward said first portion of the first electrode; a layer of programmable resistive material 16 in contact with said first portion of said first electrode; and a second electrode 28 coupled to the layer of programmable resistive material.

Regarding claim 56, MaCollum teaches in figure 1c and related text an integrated circuit device comprising:

a first conductive layer 12 on a substrate 10, wherein the first conductive layer includes at least one raised portion;

a programmable resistive material 16 in direct contact with said at least one raised portion of said first conductive layer, and

a second conductive layer 28 above said programmable resistive material.

Response to Arguments

Applicant argues that prior art does not teach a programmable resistive material 16 overlying (laying or spreading over or across) at least part of the insulative layer.

MaCollum teaches in figure 1c and related text a programmable resistive material 16 laying or spreading over or across at least part of the insulative layer. Therefore, MaCollum teaches a programmable resistive material overlying at least part of the insulative layer, as claimed.

Note that the broad recitation of the claim does not require the programmable resistive material to overlay directly above at least part of the insulative layer,

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ori Nadav whose telephone number is 571-272-1660. The examiner can normally be reached between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only.

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For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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